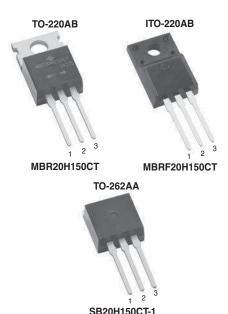


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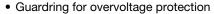
Dual Common-Cathode High-Voltage Schottky Rectifier

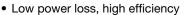
Low Leakage Current 5.0 µA



| PRIMARY CHARACTERISTICS | | | | | |
|-------------------------|----------|--|--|--|--|
| I _{F(AV)} | 2 x 10 A | | | | |
| V_{RRM} | 150 V | | | | |
| I _{FSM} | 200 A | | | | |
| V _F | 0.75 V | | | | |
| T _J max. | 175 °C | | | | |

FEATURES





Low forward voltage drop

• High frequency operation

• Solder dip 275 °C max., 10 s per JESD 22-B106

 Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC





RoHS COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency inverters, freewheeling, and polarity protection applications.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | | |
|---|-----------------------------------|--------------------|-------------|------|--|--|
| PARAMETER | | SYMBOL | MBR20H150CT | UNIT | | |
| Maximum repetitive peak reverse voltage | V_{RRM} | 150 | V | | | |
| Working peak reverse voltage | V_{RWM} | 150 | V | | | |
| Maximum DC blocking voltage | V_{DC} | 150 | V | | | |
| Maying an average few youd vestified as went | per device | I _{F(AV)} | 20 | А | | |
| Maximum average forward rectified current | per diode | | 10 | | | |
| Peak forward surge current 8.3 ms single half sine-wave s on rated load per diode | I _{FSM} | 200 | А | | | |
| Peak repetitive reverse current per diode at t _p = 2 μs, 1 kF | IRRM | 1.0 | Α | | | |
| Peak non-repetitive reverse surge energy per diode (8/20 | E _{RSM} | 10 | mJ | | | |
| Non-repetitive avalanche energy per diode at 25 °C, I _{AS} = 1 | E _{AS} | 11.25 | mJ | | | |
| Voltage rate of change (rated V _R) | | dV/dt | 10 000 | V/µs | | |
| Operating junction and storage temperature range | T _J , T _{STG} | - 65 to + 175 | °C | | | |
| Isolation voltage (ITO-220AB only) from terminals to heatsink t = 1 min | | V _{AC} | 1500 | V | | |

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| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | |
|---|-----------------------|-------------------------|-------------------------------|-------|------|
| PARAMETER | TEST CONDITIONS | | SYMBOL | VALUE | UNIT |
| Maximum instantaneous forward voltage per diode | I _F = 10 A | T _C = 25 °C | V _F ⁽¹⁾ | 0.90 | V |
| | I _F = 10 A | T _C = 125 °C | | 0.75 | |
| | I _F = 20 A | T _C = 25 °C | | 0.99 | |
| | I _F = 20 A | T _C = 125 °C | | 0.86 | |
| Maximum reverse current per diode at working peak reverse voltage | | T _J = 25 °C | I _R ⁽¹⁾ | 5.0 | μΑ |
| | | T _J = 125 °C | | 1.0 | mA |

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | |
|---|----------------|-----|------|------|------|
| PARAMETER | SYMBOL | MBR | MBRF | MBRB | UNIT |
| Typical thermal resistance per diode | $R_{	heta JC}$ | 2.2 | 4.2 | 2.2 | °C/W |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|--------------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| TO-220AB | MBR20H150CT-E3/45 | 2.06 | 45 | 50/tube | Tube | | |
| ITO-220AB | MBRF20H150CT-E3/45 | 2.20 | 45 | 50/tube | Tube | | |
| TO-262AA | SB20H150CT-1E3/45 | 1.58 | 45 | 50/tube | Tube | | |

Note

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

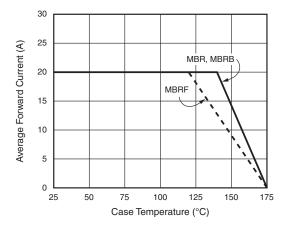


Fig. 1 - Forward Derating Curve (Total)

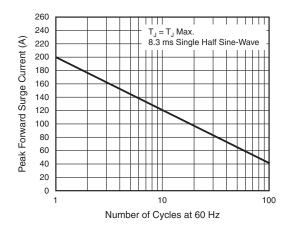


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

⁽¹⁾ AEC-Q101 qualified



10 000

1000

100

10

1

0.1

0.01

T_J = 175 °C

Instantaneous Reverse Current (µA)

MBR20H150CT, MBRF20H150CT, SB20H150CT-1

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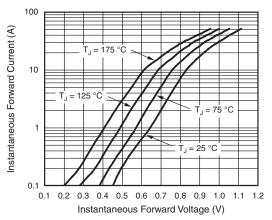
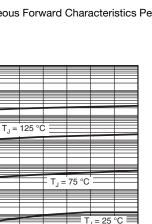


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode



90

Percent of Rated Peak Reverse Voltage (%)
Fig. 4 - Typical Reverse Characteristics Per Diode

40 50 60

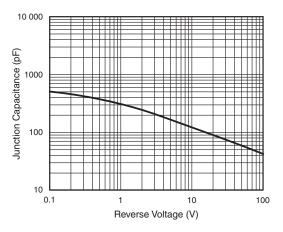


Fig. 5 - Typical Junction Capacitance Per Diode

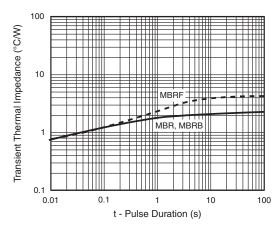
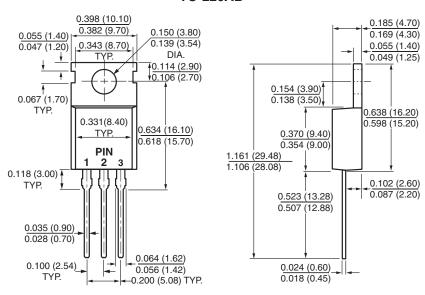


Fig. 6 - Typical Transient Thermal Impedance Per Diode

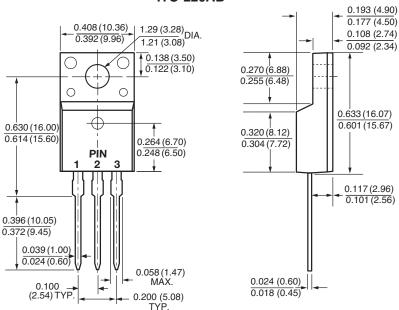
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB



ITO-220AB

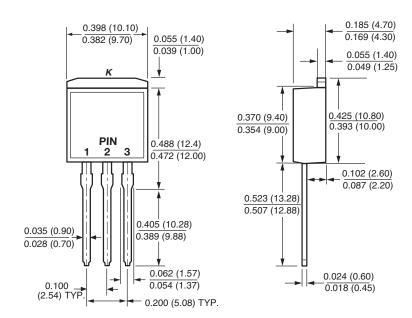




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TO-262AA





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